

Taiwan Semiconductor

25A, 35V - 150V Schottky Barrier Surface Mount Rectifier

FEATURES

TAIWAN

• Low power loss, high efficiency

EMICONDUCTOR

- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

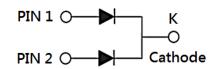
KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	25	А		
V _{RRM}	35 - 150	V		
I _{FSM}	200	А		
T _{J MAX}	150	°C		
Package	TO-263AB	(D ² PAK)		
Configuration	Dual d	lies		







TO-263AB (D²PAK)



ABSOLUTE MAXIMUM R		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	2535	2545	2550	2560	2590	25100		UNIT
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Marking code on the device		MBRS 2535CT	MBRS 2545CT	MBRS 2550CT	MBRS 2560CT	MBRS 2590CT	MBRS 25100CT	MBRS 25150CT	
Repetitive peak reverse voltage	V _{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	V _{R(RMS)}	24	31	35	42	63	70	105	V
Forward current	I _F				25				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}		200					А	
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		1 0.5					А	
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	25					A		
Critical rate of rise of off- state voltage	dv/dt	10,000					V/µs		

Notes:

1. $tp = 2.0\mu s$, 1.0KHz



MBRS2535CT – MBRS25150CT Taiwan Semiconductor

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MBRS 2535 CT	MBRS 2545 CT	MBRS 2550 CT	MBRS 2560 CT	MBRS 2590 CT	MBRS 25100 CT	MBRS 25150 CT	UNIT
Junction temperature	T_J	-55 to +150			°C				
Storage temperature	T _{STG}				-55 to +1	50			°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R _{eJC}	1	°C/W

PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	MBRS2535CT MBRS2545CT	I _F = 12.5A, T _J = 25°C		-	0.65	V
	MBRS2550CT MBRS2560CT			-	0.75	V
	MBRS2590CT MBRS25100CT			-	0.85	V
	MBRS25150CT			-	0.95	V
Forward voltage per diode ⁽¹⁾ MBRS2554 MBRS2556 MBRS2550 MBRS2510 MBRS2515 MBRS254 MBRS254 MBRS2556 MBRS256	MBRS2535CT MBRS2545CT			-	0.82	V
	MBRS2550CT MBRS2560CT		V _F	-	0.90	V
	MBRS2590CT MBRS25100CT			-	0.92	V
	MBRS25150CT			-	1.02	V
	MBRS2535CT MBRS2545CT			-	0.55	V
	MBRS2550CT MBRS2560CT			-	0.65	V
	MBRS2590CT MBRS25100CT			-	0.75	V
	MBRS25150CT			-	0.92	V
	MBRS2535CT MBRS2545CT			-	0.73	V
	MBRS2550CT MBRS2560CT	I _F = 25.0A, T _J = 125°C		-	0.80	V
MBRS	MBRS2590CT MBRS25100CT	90CT 00CT		-	0.88	V
	MBRS25150CT			-	0.98	V



PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
		T _J = 25°C		-	200	μA
Reverse current @ rated V _R per diode ⁽²⁾	MBRS2590CT MBRS25100CT MBRS25150CT		I _R	-	100	μA
	MBRS2535CT MBRS2545CT	T _J = 125°C		-	15	mA
	MBRS2550CT MBRS2560CT			-	10	mA
	MBRS2590CT MBRS25100CT			-	7.5	mA
	MBRS25150CT			-	5	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING			
MBRS25xCT	TO-263AB (D ² PAK)	800 / Tape & Reel			

Notes:

1. "x" defines voltage from 35V(MBRS2535CT) to 150V(MBRS25150CT)



MBRS2535CT – MBRS25150CT

Taiwan Semiconductor

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

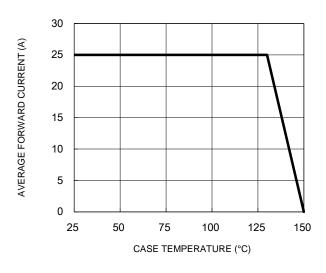


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

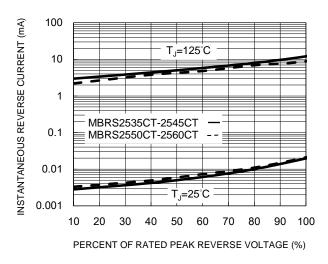
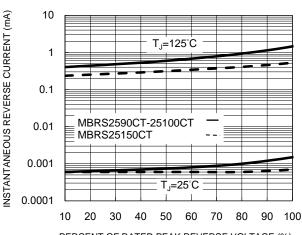


Fig.5 Typical Reverse Characteristics



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

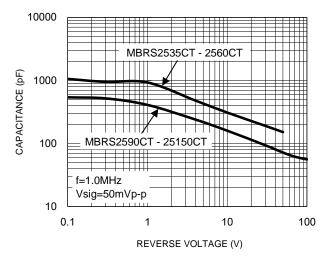


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics

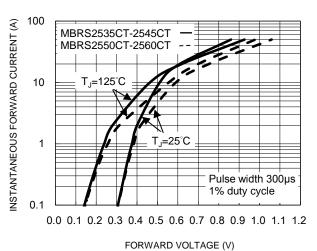
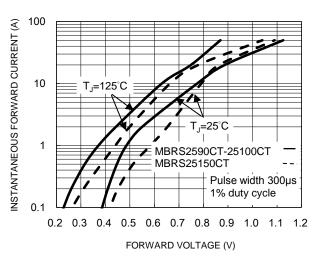


Fig.6 Typical Forward Characteristics





Taiwan Semiconductor

CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

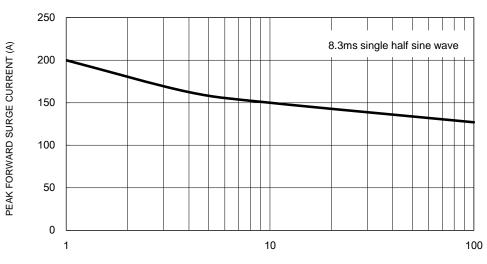
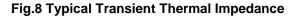
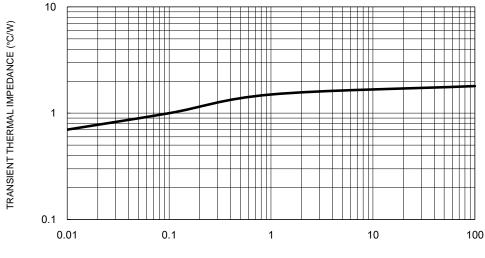


Fig.7 Maximum Non-Repetitive Forward Surge Current

NUMBER OF CYCLES AT 60 Hz





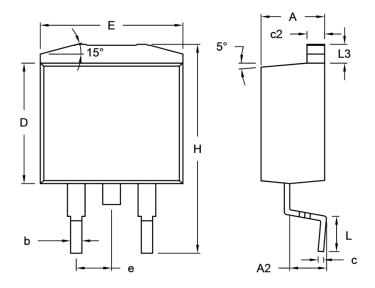
PULSE DURATION (s)

MBRS2535CT – MBRS25150CT

Taiwan Semiconductor

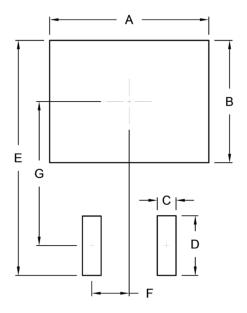
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM.	Unit	Unit (mm)		(inch)
	Min.	Max.	Min.	Max.
A	4.44	4.70	0.175	0.185
A2	2.03	2.79	0.080	0.110
b	0.68	0.94	0.027	0.037
с	0.36	0.53	0.014	0.021
c2	1.14	1.40	0.045	0.055
D	8.25	9.25	0.325	0.364
E	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
н	14.60	15.88	0.575	0.625
L	2.29	2.79	0.090	0.110
L3	1.14	1.40	0.045	0.055

SUGGESTED PAD LAYOUT



Unit (mm) Unit (inch) Symbol Α 10.80 0.425 В 0.327 8.30 С 1.27 0.050 D 4.05 0.159 Е 15.95 0.628 F 2.54 0.100 G 9.775 0.385

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



MBRS2535CT - MBRS25150CT

Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.